No.1905B

DS441

Silicon Planar Type

Low Leak Switching Diode

-65 to +175

## **Features**

- · Glass sleeve structure: DHD type
- Low leak current :  $I_R = -10nA$  max. Power dissipation : P = 300mW max.
- · Interterminal capacitance: C=6.0pF max.

| Absolute Maximum Ratings at Ta = 25°C |                        |             |      | unit |
|---------------------------------------|------------------------|-------------|------|------|
| Peak Reverse Voltage                  | $V_{\mathbf{RM}}$      |             | - 35 | V    |
| Reverse Voltage                       | $V_{ m R}$             |             | -30  | V    |
| Peak Forward Current                  | $I_{FM}$               |             | 300  | mΑ   |
| Average Rectified Current             | $I_{O}$                |             | 100  | mA   |
| Surge Forward Current                 | $I_{FSM}$              | 1 sec pulse | 1000 | mA   |
| Power Dissipation                     | P                      | -           | 300  | mW   |
| Junction Temperature                  | $\mathbf{T}\mathbf{j}$ |             | 175  | °C   |

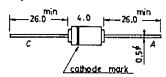
Tstg

Electrical Characteristics at Ta = 25°C

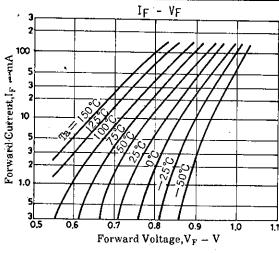
Storage Temperature

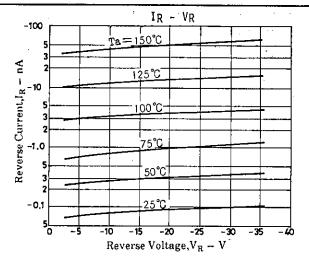
| recurrent characteristics at 1a - 20 C |                  |                       | mm ty        | ) max | unit |
|--|------------------|-----------------------|--------------|-------|------|
| Forward Voltage                        | $V_{\mathbf{F}}$ | $I_F = 100 \text{mA}$ | 1.0          | 1.3   | V    |
| Reverse Current                        | $I_{\mathbf{R}}$ | $V_R = -30V$          | <b>-0</b> .1 | -10   | nА   |
| Interterminal Capacitance              | C                | $V_R = 0V, f = 1MHz$  | 3.0          | 6.0   | pF   |

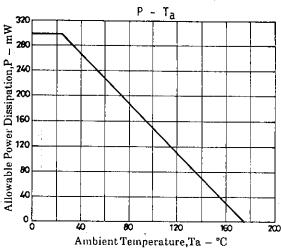
Package Dimensions 1080 (unit: mm)



C: Cathode A: Anode







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